SI2308
60V N-Channel Trench Power MOSFET

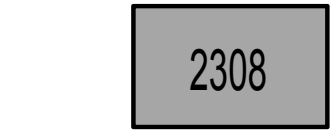
V_{DSS}	60 V
I_D	3 A
$R_{DS(ON)}$	75mΩ

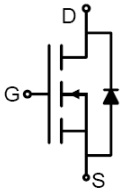
Features

Low Gate Charge
High Power and current handing capability
Lead free product is acquired

Application

PWM Applications
Load Switch
Power Management





Schematic Diagram



SOT-23-3L top view

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings

Symbol	Parameter	Limit	Unit
V_{DS}	Drain-Source Voltage (V_{GS}=0V)	60	V
V_{GS}	Gate-Source Voltage (V_{DS}=0V)	±20	V
I_D	Drain Current-Continuous(T_A=25℃)	3	A
	Drain Current-Continuous(T_A=100℃)	1.9	A
$I_{DM\ (pluse)}$	Drain Current-Continuous@ Current-Pulsed (Note 1)	12	A
P_D	Maximum Power Dissipation(T_A=25℃)	1.5	W
	Maximum Power Dissipation(T_A=100℃)	0.6	W
E_{AS}	Avalanche energy (Note 2)	12	mJ
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 150	℃

Thermal Characteristic

Symbol	Parameter	Typ	Max	Unit
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient		83	℃/W

Electrical Characteristics (T_J=25℃unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
On/Off States						
BV_{DSS}	Drain-Source Breakdown Voltage	V_{GS}=0V I_D=250μA	60			V
I_{DSS}	Zero Gate Voltage Drain Current	V_{DS}=60V, V_{GS}=0V T_J=25℃			1	μA
		V_{DS}=60V, V_{GS}=0V T_J=125℃			100	μA
I_{GSS}	Gate-Body Leakage Current	V_{GS}=±20V, V_{DS}=0V			±100	nA
$V_{GS(th)}$	Gate Threshold Voltage	V_{DS}=V_{GS}, I_D=250μA	1		2.5	V
g_{FS}	Forward Transconductance	V_{DS}=5V, I_D=2A		4.1		S
$R_{DS(ON)}$	Drain-Source On-State Resistance	V_{GS}=10V, I_D=2A T_J=25℃		75	85	mΩ
$R_{DS(ON)}$	Drain-Source On-State Resistance	V_{GS}=4.5V, I_D=1.5A T_J=25℃		90	100	mΩ
Dynamic Characteristics						
C_{iss}	Input Capacitance	V_{DS}=30V,V_{GS}=0V, f=1.0MHz		369		pF
C_{oss}	Output Capacitance			28		pF
C_{rss}	Reverse Transfer Capacitance			22		pF
R_g	Gate resistance	V_{GS}=0V, V_{DS}=0V, f=1.0MHz		0.78		Ω
Switching Parameters						
$t_{d(on)}$	Turn-on Delay Time	V_{GS}=10V, V_{DS}=30V, R_L=15Ω, R_{GEN}=3Ω		5		nS
t_r	Turn-on Rise Time			8		nS
$t_{d(off)}$	Turn-Off Delay Time			36		nS
t_f	Turn-Off Fall Time			21		nS
Q_g	Total Gate Charge	V_{GS}=10V, V_{DS}=30V, I_D=2A		9		nC
Q_{gs}	Gate-Source Charge			1.6		nC
Q_{gd}	Gate-Drain Charge			2		nC
Source-Drain Diode Characteristics						
I_{SD}	Source-Drain Current (Body Diode)				3	A
V_{SD}	Forward on Voltage (Note 3)	V_{GS}=0V, I_S=2A			1.2	V
t_{rr}	Reverse Recovery Time	I_F=2A, dI/dt=100A/μs		20		ns
Q_{rr}	Reverse Recovery Charge	I_F=2A, dI/dt=100A/μs		8		nC

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature.
Notes 2.E_{AS} condition: T_J=25℃,V_{DD}=40V,V_G=10V, Rg=25Ω, L=0.5mH.

RATING AND CHARACTERISTIC CURVES

Figure 1. Output Characteristics

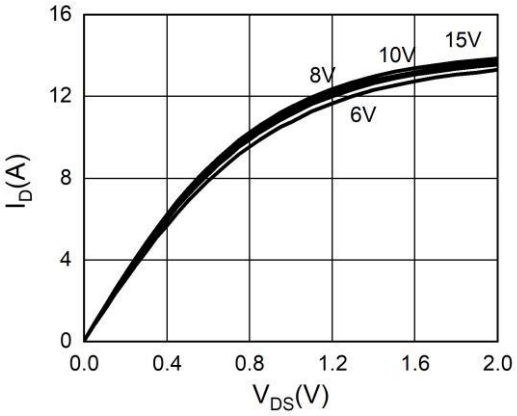


Figure 2. Transfer Characteristics

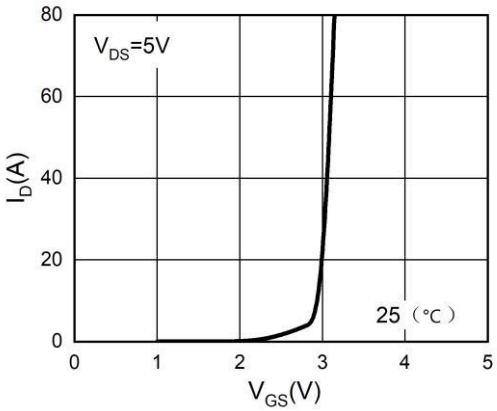


Figure 3. Power Dissipation

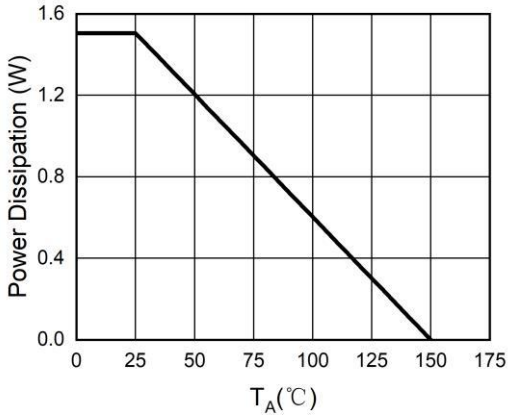


Figure 4. Drain Current

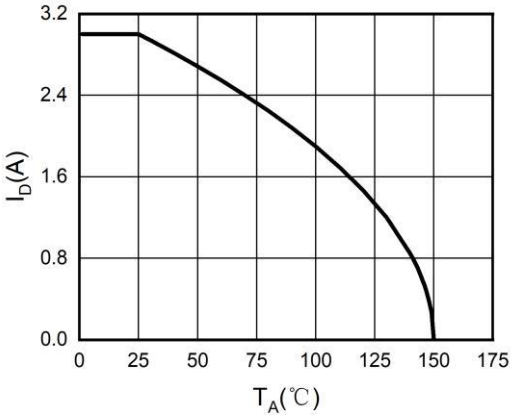


Figure 5. BV_{DSS} vs Junction Temperature

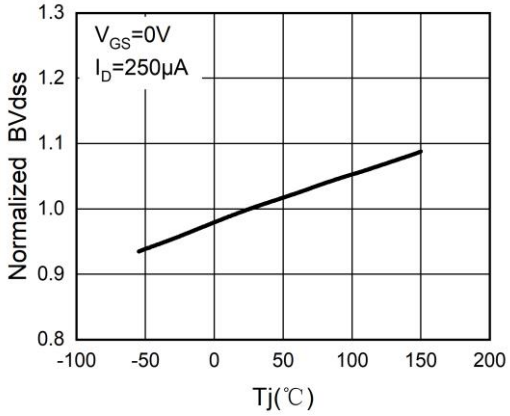
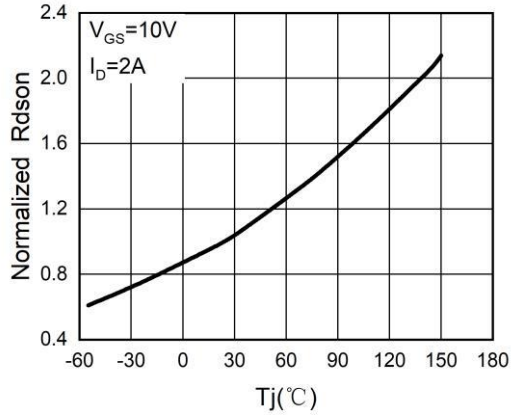


Figure 6. $R_{DS(ON)}$ vs Junction Temperature



RATING AND CHARACTERISTIC CURVES

Figure 7. Gate Charge Waveforms

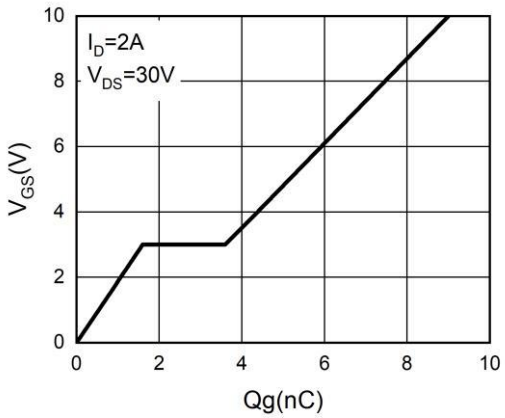


Figure 8. Capacitance

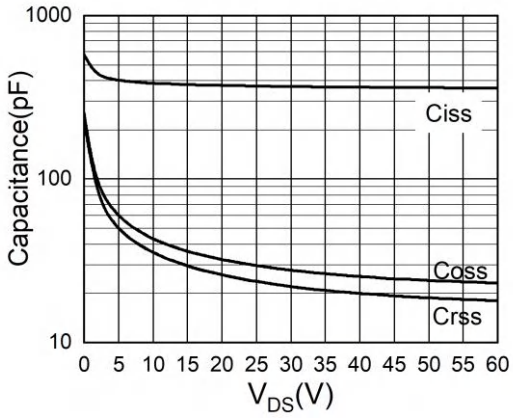


Figure 9. Body-Diode Characteristics

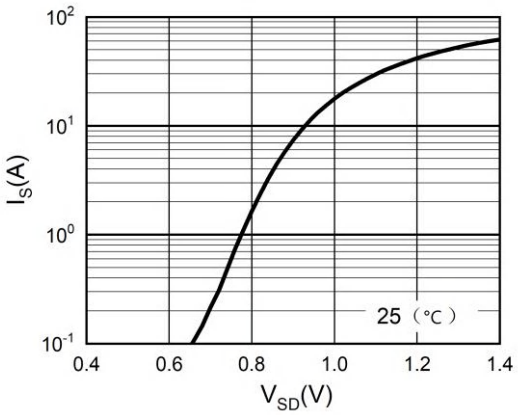
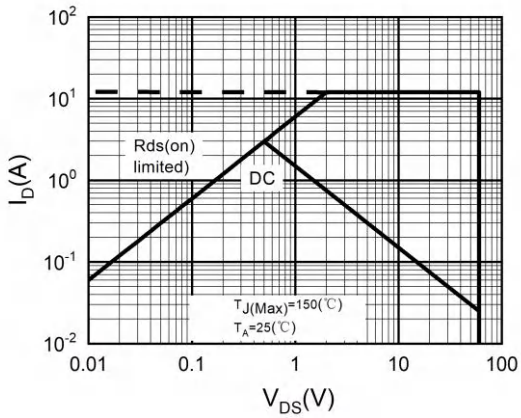


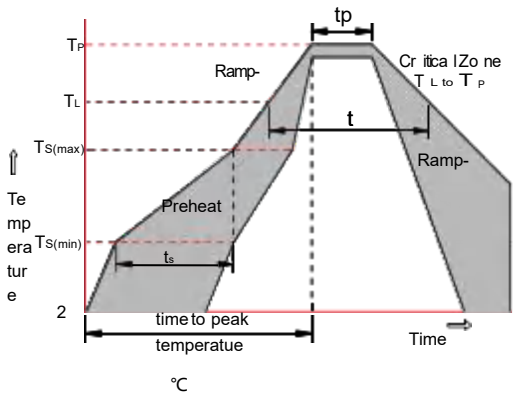
Figure 10. Maximum Safe Operating Area



Soldering parameters

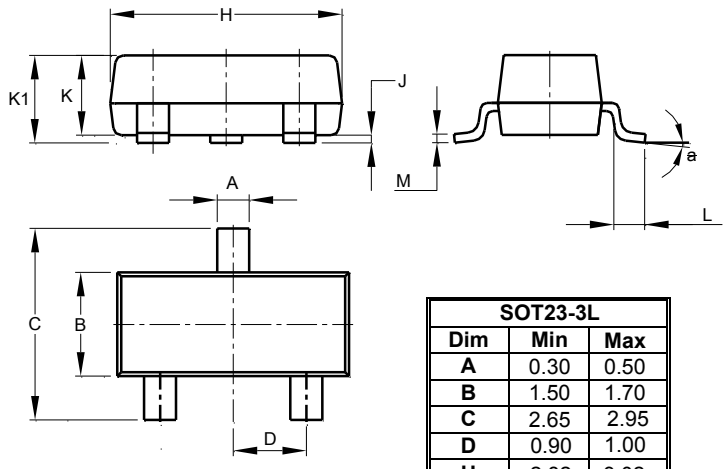
Reflow Condition		Pb-Free assembly (see as bellow)
Pre Heat	-Temperature Min ($T_{s(min)}$)	+150℃
	-Temperature Max($T_{s(max)}$)	+200℃
	-Time (Min to Max) (ts)	60-180 secs.
Average ramp up rate (Liquid us Temp (T_L) to peak)		3℃/sec. Max
$T_{s(max)}$ to T_L - Ramp-up Rate		3℃/sec. Max
Reflow	-Temperature(T_L)(Liquid us)	+217℃
	-Temperature(t_L)	60-150 secs.
Peak Temp (T_p)		+260(+0/-5)℃
Time within 5℃ of actual Peak Temp (t_p)		30 secs. Max
Ramp-down Rate		6℃/sec. Max
Time 25℃ to Peak Temp (T_P)		8 min. Max
Do not exceed		+260℃

FIG5: Reflow condition

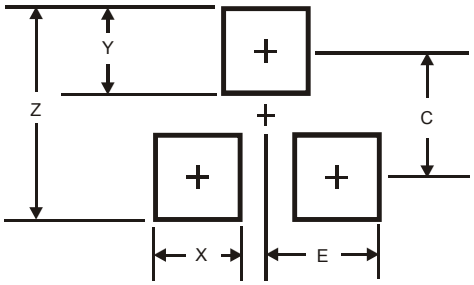


Package Dimensions & Suggested Pad Layout

SOT23-3L



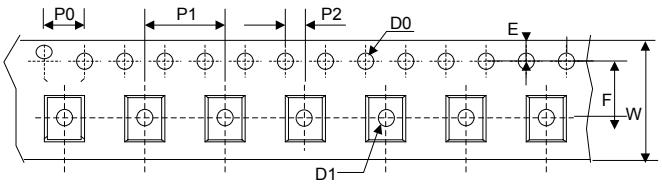
SOT23-3L		
Dim	**Min**	**Max**
A	0.30	0.50
B	1.50	1.70
C	2.65	2.95
D	0.90	1.00
H	2.82	3.02
J		0.10
K	1.05	1.15
K1	1.05	1.25
L	0.30	0.60
M	0.10	0.20
a	0°	8°
All Dimensions in mm		

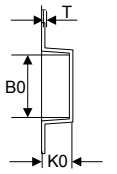


Dimensions	SOT23-3L
Z	3.3
X	0.9
Y	1.0
C	2.3
E	1.40

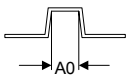
Tape & rell specification

Tape





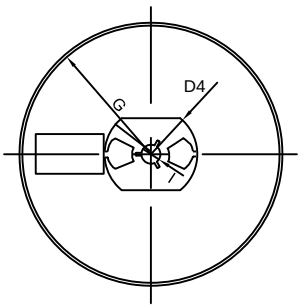
SECTION : B-B

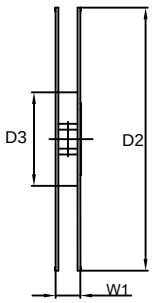


SECTION : A-A

Symbol	Dimension (mm)
P0	4.00±0.20
P1	4.00±0.20
P2	2.00±0.20
D0	1.55±0.20
D1	1.05±0.20
E	1.55±0.20
F	3.60±0.20
W	8.00±0.20
A0	3.80±0.20
B0	3.50±0.20
K0	1.55±0.20
T	0.25±0.15

7” Reel





D2	178.0±5.0
D3	55Min.
D4	R24.0±3.0
G	R82.0±3.0
I	13.0±2.0
W1	11.0±3.0
Quantity: 3000PCS	